



LT1120M/883

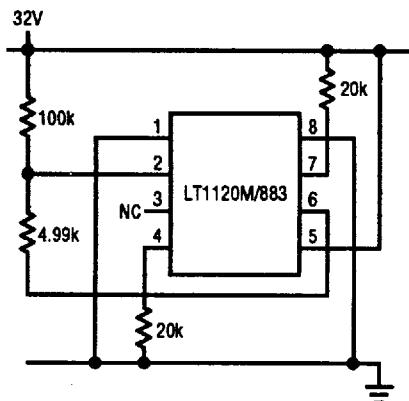
Micropower Regulator with Comparator and Shutdown

DESCRIPTION

The LT1120M/883 is a combination micropower positive regulator and free collector comparator on a single monolithic chip. With only 40 μ A supply current, the LT1120M/883 can supply over 125mA of output current. Input voltage range is from 4.5V to 36V and dropout voltage is 0.6V at 125mA. Dropout voltage decreases with lower load currents. Also included on the chip is a Class B output 2.5V reference that can either source or sink current. Shutdown pin allows logic shutdown of the output.

The comparator can be used for system or battery monitoring. For example, the comparator can be used to warn of low system voltage.

BURN-IN CIRCUIT



The 2.5V reference will source or sink current. This allows it to be used as a supply splitter or auxiliary output.

The device is processed to the requirements of MIL-STD-883 Class B to yield circuits usable in precision military applications.

ABSOLUTE MAXIMUM RATINGS

Input Voltage Transient	36V
NPN Collector Voltage	36V
Output Short-Circuit Duration	Indefinite
Power Dissipation	Internally Limited
Operating Temperature Range	-55°C to 125°C
Storage Temperature Range	-65°C to 150°C

PACKAGE/ORDER INFORMATION

TOP VIEW	ORDER PART NUMBER
 J8 PACKAGE 8-LEAD CERAMIC DIP	LT1120MJ8/883
PART MARKINGS [†]	
	LT1120MJ8/883C
TOP VIEW	ORDER PART NUMBER
 H PACKAGE 8-LEAD TO-5 METAL CAN	LT1120MH/883
PART MARKINGS [†]	
	LT1120MH/883C

[†] The suffix letter "C" of the part mark indicates compliance per MIL-STD-883, para 1.2.1.1.

TABLE 1: ELECTRICAL CHARACTERISTICS

PARAMETER	CONDITIONS	$T_A = 25^\circ\text{C}$			SUB-GROUP	$-55^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$			SUB-GROUP	UNITS
		MIN	TYP	MAX		MIN	TYP	MAX		
Reference										
Reference Voltage	$4.5V \leq V_{IN} \leq 36V$	2.46	2.5	2.54	1	2.4	2.5	2.55	2,3	V
Line Regulation	$4.5V \leq V_{IN} \leq 36V$	0.01	0.015		1	0.01	0.02		2,3	%/V



LT1120M/883

TABLE 1: ELECTRICAL CHARACTERISTICS

PARAMETER	CONDITIONS	$T_A = 25^\circ C$			SUB-GROUP	$-55^\circ C \leq T_A \leq 125^\circ C$			SUB-GROUP	UNITS
		MIN	TYP	MAX		MIN	TYP	MAX		
Load Regulation	$-2mA \leq I_{REF} \leq 2mA, V_{IN} = 12V$	0.2	0.6	1		0.3	0.8	2,3		%
Output Source Current	$V_{IN} = 5V$	2	4		1	2		2,3		mA
Output Sink Current	$V_{IN} = 5V$	2	4		1	2		2,3		mA
Temperature Stability			1							%
Regulator										
Supply Current	$V_{IN} = 6V, I_{OUT} \leq 100\mu A$	45	80		1	65	95	2,3		μA
	$V_{IN} = 36V, I_{OUT} \leq 100\mu A$	75	100		1	85	100	2,3		μA
	$V_{IN} = 12V, I_{OUT} \leq 125mA$	11	20		1	11	20	2,3		mA
Output Current	$(V_{IN} - V_{OUT}) \geq 1V, V_{IN} \geq 6V$	125			1	125		2,3		mA
Load Regulation	$(V_{IN} - V_{OUT}) \geq 1V, V_{IN} \geq 6V$	0.2	0.5		1	1		2,3		%
Line Regulation	$6V \leq V_{IN} \leq 36V$	0.01	0.015		1	0.02		2,3		%/V
Dropout Voltage	$I_{OUT} = 100\mu A$	0.02	0.05		1	0.06		2,3		V
	$I_{OUT} = 125mA$	0.40	0.65		1	0.85		2,3		V
Feedback Sense Voltage	$V_{IN} = 12V$	2.44	2.5	2.56	1	2.38	2.5	2.57	2,3	V
Shutdown Pin Voltage	Normal $V_{OUT} \leq 0.5V$ Shutdown	2.2	1.4		1					V V
Feedback Bias Current		15	40		1	50		2,3		nA
Minimum Load Current	$V_{IN} = 36V$	1	5		1	50		2,3		μA
Short-Circuit Current	$V_{IN} = 36V$	300	400		1	300	400	2,3		mA
Comparator										
Offset Voltage	$0V \leq V_{CM} \leq 35V, V_{IN} = 36V$	3	7		1	10		2,3		mV
Bias Current	$0V \leq V_{CM} \leq 35V, V_{IN} = 36V$ (Note 1)	15	40		1	15	60	2,3		nA
Gain-NPN Pulldown	$\Delta V_{OUT} = 29V, R_L = 20k$	2000	10000		1	1000		2,3		V/V
Common-Mode Rejection	$0V \leq V_{CM} \leq 35V, V_{IN} = 36V$	80	94		1					dB
Power Supply Rejection	$4.5V \leq V_S \leq 36V$	80	96		1			2,3		dB
Output Sink Current	$V_{IN} = 4.5V$ (Note 2)	10	18		1	5	10	2,3		mA
Saturation Voltage	$I_{OUT} = 1mA$	0.4	0.6		1					V
Input Voltage Range		0	$V_{IN} - 1$		1					V
Response Time			5							μs
Leakage Current			2		1	8		2,3		μA

Note 1: For $0V \leq V_{CM} \leq 0.1V$ and $T > 85^\circ C$ $I_{BIAS MAX}$ is 100nA.

Note 3: Devices are tested to 36V on a pulse power basis. This device is rated

Note 2: For $T_A \leq -40^\circ C$ output sink current min is 2.5mA

steady state to 30V.

TABLE 2: ELECTRICAL TEST REQUIREMENTS

MIL-STD-883 TEST REQUIREMENTS	SUBGROUP
Final Electrical Test Requirements (Method 5004)	1*, 2,3
Group A Test Requirements (Method 5005)	1,2,3
Group C and D End Point Electrical Parameters (Method 5005)	1

* PDA applies to subgroup 1. See PDA Test Notes.

PDA Test Notes

The PDA is specified as 5% based on failures from group A, subgroup 1, tests after cooldown as the final electrical test in accordance with method 5004 of MIL-STD-883 Class B. The verified failures of group A, subgroup 1, after burn-in divided by the total number of devices submitted for burn-in in that lot shall be used to determine the percent for the lot.

Linear Technology Corporation reserves the right to test to tighter limits than those given.

I.D. No. 66-10-0180 Rev. A 01/25/93